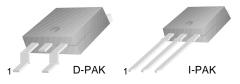


KSH112

D-PAK for Surface Mount Applications

- High DC Current Gain
- Built-in a Damper Diode at E-C
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I-PAK, " I " Suffix)
- Electrically Similar to Popular TIP112

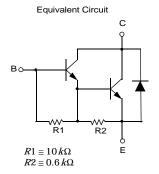


1.Base 2.Collector 3.Emitter

NPN Silicon Darlington Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	100	V
V _{CEO}	Collector-Emitter Voltage	100	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	2	Α
I _{CP}	Collector Current (Pulse)	4	Α
I _B	Base Current	50	mA
P _C	Collector Dissipation (T _C =25°C)	20	W
	Collector Dissipation (T _a =25°C)	1.75	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C



Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage	$I_C = 30 \text{mA}, I_B = 0$	100		V
I _{CEO}	Collector Cut-off Current	$V_{CE} = 50V, I_{B} = 0$		20	μΑ
I _{CBO}	Collector Cut-off Current	$V_{CB} = 100V, I_B = 0$		20	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$		2	mA
h _{FE}	* DC Current Gain	$V_{CE} = 3V, I_{C} = 0.5A$	500		
		$V_{CE} = 3V, I_{C} = 2A$	1000	12K	
		$V_{CE} = 3V$, $I_C = 4A$	200		
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_{C} = 2A, I_{B} = 8mA$		2	V
		$I_C = 4A, I_B = 40mA$		3	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	$I_C = 4A, I_B = 40mA$		4	V
V _{BE} (on)	* Base-Emitter On Voltage	$V_{CE} = 3A$, $I_C = 2A$		2.8	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.75A$	25		MHz
C _{ob}	Output Capacitance	$V_{CB} = 10V, I_{E} = 0$		100	pF
		f = 0.1MHz			

^{*} Pulse Test: PW≤300μs, Duty Cycle≤2%

Typical Characteristics

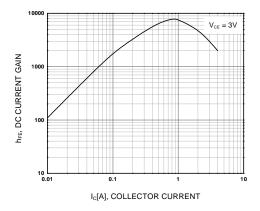


Figure 1. DC current Gain

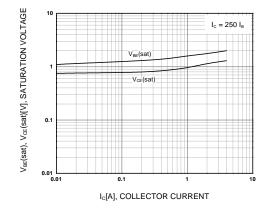


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

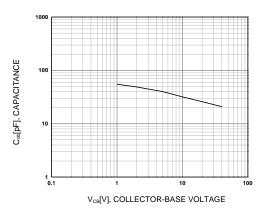


Figure 3. Collector Output Capacitance

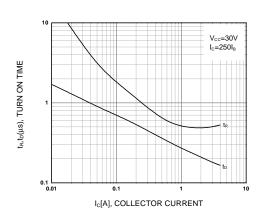


Figure 4. Turn On Time

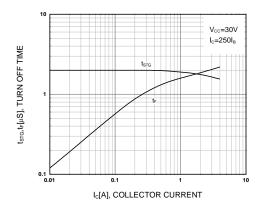


Figure 5. Turn Off Time

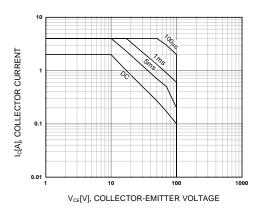


Figure 6. Safe Operating Area

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Typical Characteristics (Continued)

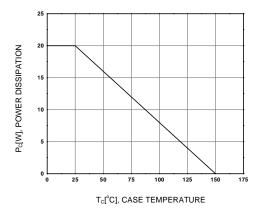
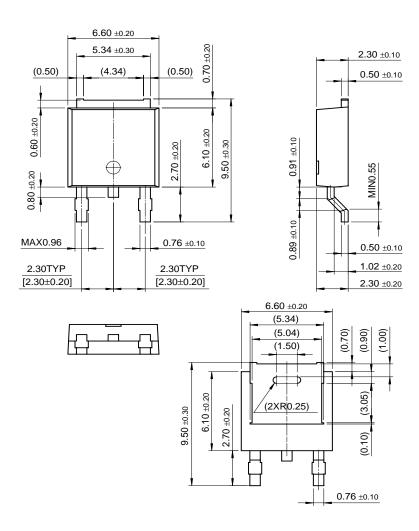


Figure 7. Power Derating

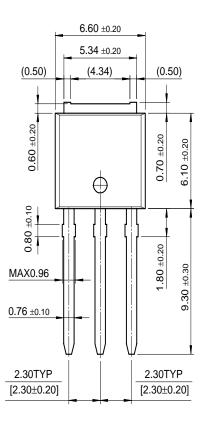
Package Dimensions

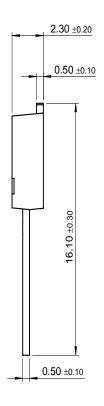
D-PAK

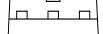


Package Dimensions (Continued)

I-PAK







Dimensions in Millimeters

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